TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SC5445

HORIZONTAL DEFLECTION OUTPUT FOR HIGH RESOLUTION

DISPLAY, COLOR TV

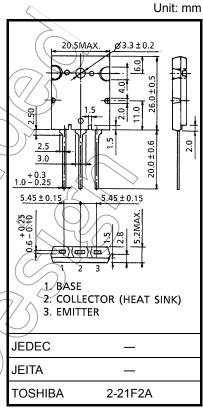
HIGH SPEED SWITCHING APPLICATIONS

High Voltage : V_{CBO} = 1500 V
 Low Saturation Voltage : V_{CE} (sat) = 3 V (Max.)
 High Speed : t_E(2) = 0.1 us (Typ.)

• High Speed : $t_f(2) = 0.1 \mu s$ (Typ.)

ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	1500	> V
Collector-Emitter Voltage		V _{CEO}	600	V
Emitter-Base Voltage		V _{EBO}	5	V
Collector Current	DC	lc <	20	A
	Pulse	ICP	40	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Base Current		IB((10	A
Collector Power Dissipation		Po	200	w
Junction Temperature		(T_j)	150	\/°C
Storage Temperature Range		T _{stg}	-55~150	\$) }



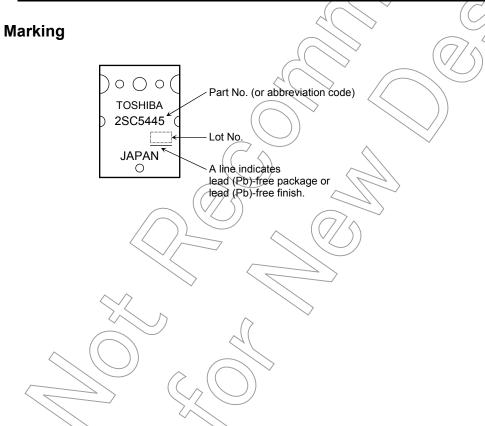
Weight: 9.75 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

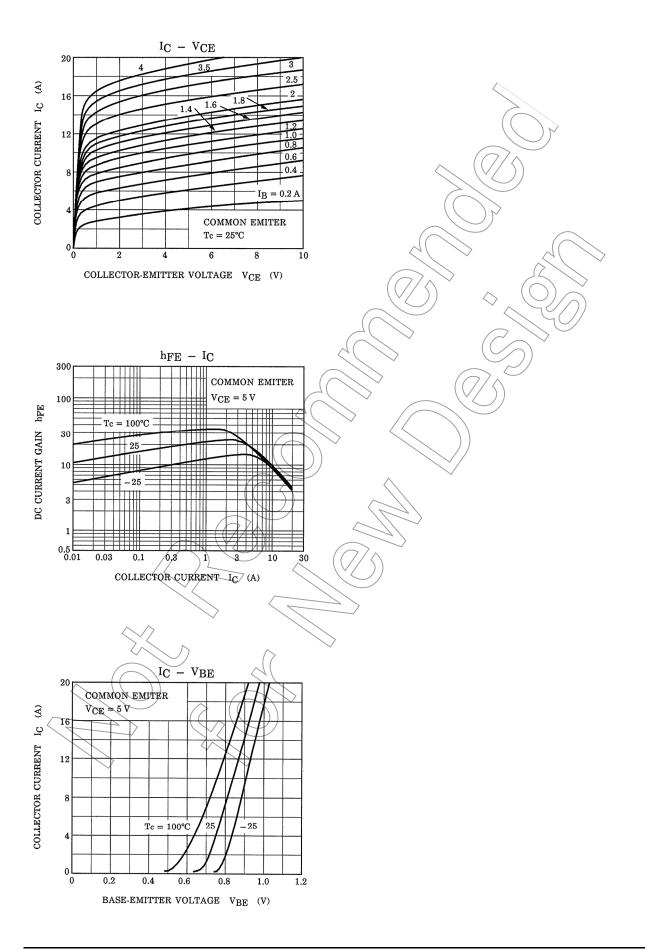
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

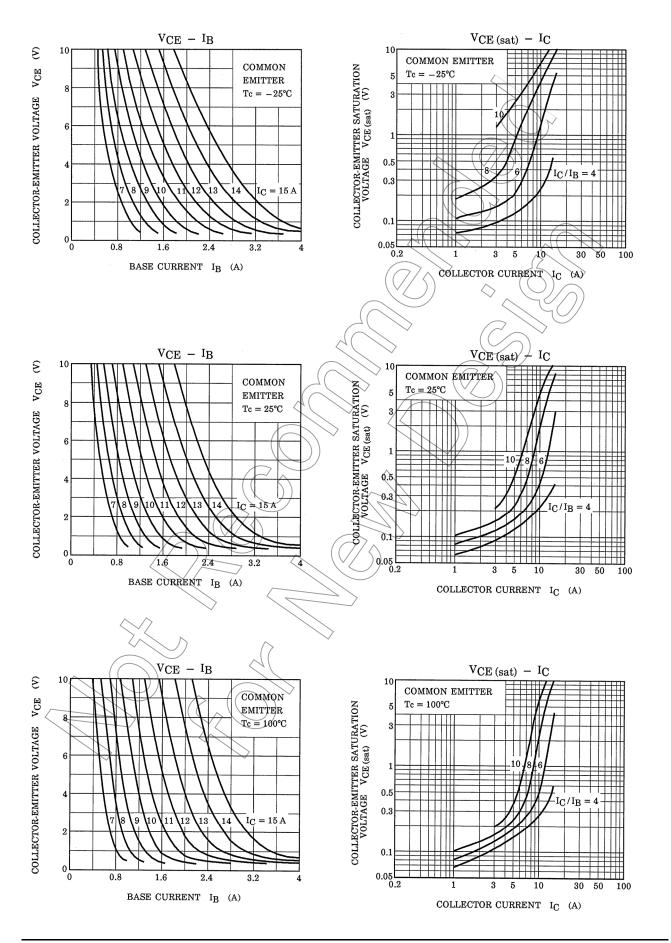
CHARAC	CTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Collector Cut-off	Current	I _{CBO}	V _{CB} = 1500 V, I _E = 0	_	_	1	mA	
Emitter Cut-off C	urrent	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	10	μΑ	
Emitter-Base Bre	eakdown Voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	600	_	_	V	
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 2 A	10	_	40	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 10 A	1) }	14.5		
		h _{FE (3)}	V _{CE} = 5 V, I _C = 15 A	4.5	/_	8.5		
Collector-Emitter	Saturation Voltage	V _{CE} (sat)	I _C = 15 A, I _B = 3.75 A	(\mathcal{L})	_	3	V	
Base-Emitter Sat	turation Voltage	V _{BE} (sat)	I _C = 15 A, I _B = 3.75 A		1.0	1.5	V	
Transition Freque	ency	f _T	V _{CE} = 10 V, I _C = 0.1 A) ⁷ –	1.7	_	MHz	
Collector Output	Capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	290	_	pF	
Switching Time	Storage Time	t _{stg (1)}	I _{CP} = 10 A, I _{B1} (end) = 1.7 A	_	2.5	3.5		
	Fall Time	t _{f (1)}	f _H = 64 kHz	- (0,12	0.3	μs	
	Storage Time	t _{stg (2)}	I _{CP} = 8 A, I _{B1} (end) = 1.4 A	> _ (2.0	2.2	116	
	Fall Time	t _{f (2)}	f _H = 100 kHz		0:10	0.15	μs	

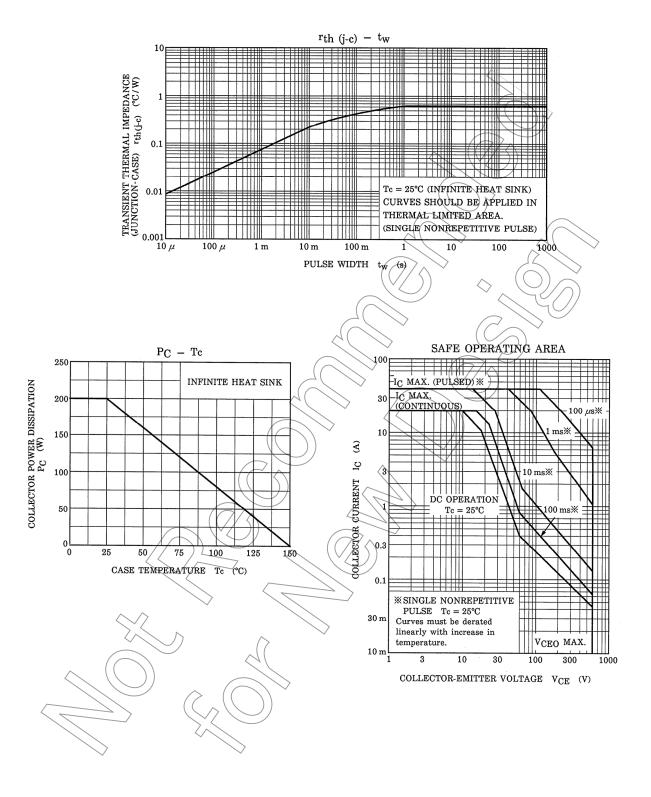


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